

Investigation of Al droplet wetting behavior on highly-oriented SiC

Song ZHANG¹, Kaixin ZUO², Pengjian LU^{2,3}, Qingfang XU^{1,*}, Meijun YANG¹,
Kai LIU², Rong TU^{1,4}

¹State Key Laboratory of Advanced Technology for Materials Synthesis and Processing, Wuhan University of Technology, 122 Luoshi Road, Wuhan 430070, People's Republic of China

²School of Materials Science and Engineering, Wuhan University of Technology, 122 Luoshi Road, Wuhan 430070, People's Republic of China

³Wuhan Tuocai Technology Co., Ltd., 147 Luoshi Road, Wuhan 430070, People's Republic of China

⁴Chaozhou Branch of Chemistry and Chemical Engineering Guangdong Laboratory, Chaozhou 521000, People's Republic of China

*Corresponding author, Qingfang XU; E-mail: xuqingfanghed@163.com

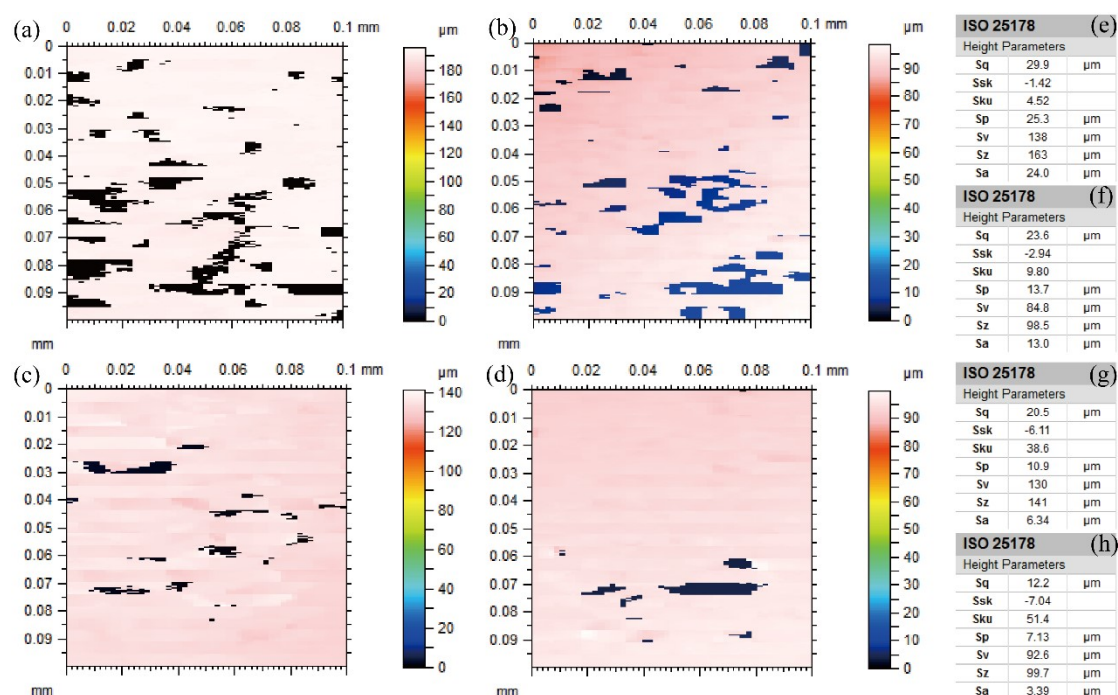


Fig. S1. (a)-(d), surface roughness topographies of samples A, A1 and samples B, B1, (e)-(h), roughness values corresponding to samples A, A1 and samples B, B1.

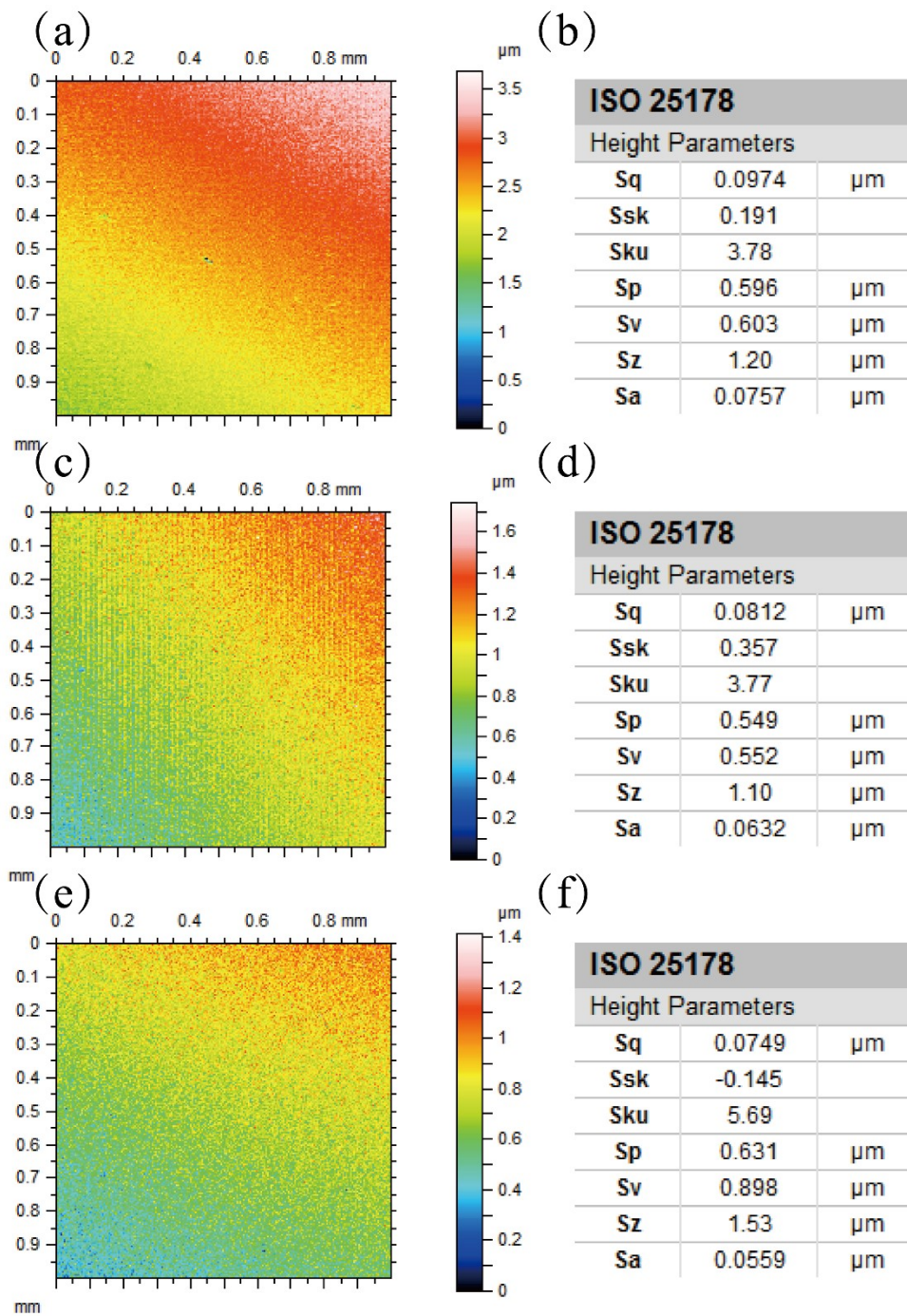


Fig. S2. Morphological plot of surface roughness of samples A, B and C after polishing and their corresponding average roughness values. (a), (d), sample A, (b), (e), sample B, (c), (f), sample C.